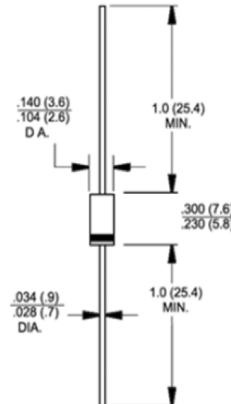


Features

2018

- Metal-Semiconductor junction with guardring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

**DO-204AC (DO-15)****Dimensions in inches and (millimeters)****Mechanical Data**

- Case: JEDEC DO-204AC(DO-15) molded plastic
- Polarity: Color band denotes cathode end
- Weight: 0.014 ounce, 0.39 gram
- Mounting position: Any

MAXIMUM RATINGS and ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

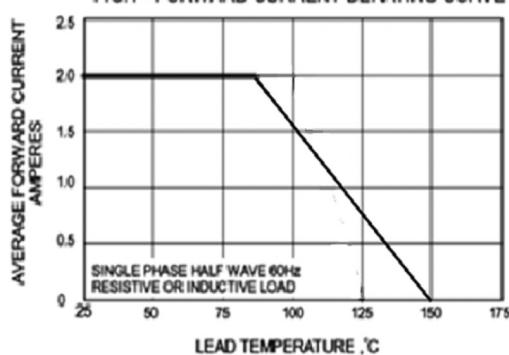
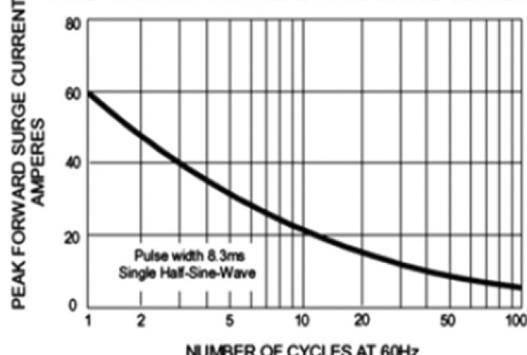
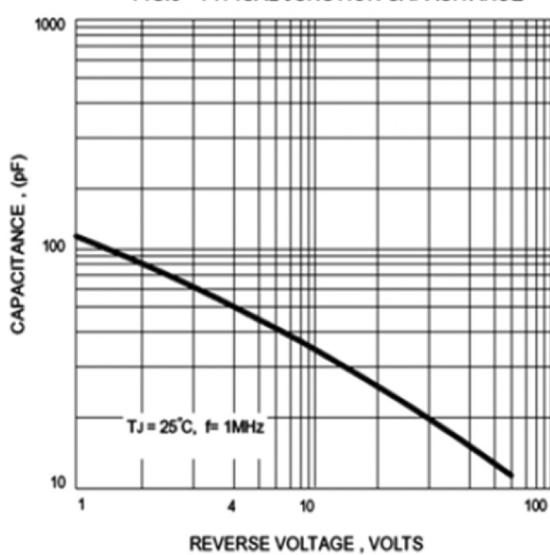
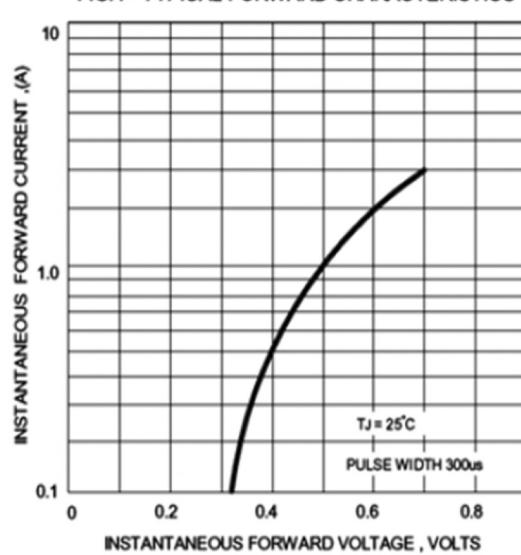
Single phase, half wave, 60HZ, resistive or inductive load.

For capacitive load, derate current by 20%

PARAMETER	SYMBOL	SB270	SB280	SB290	SB2B0	UNIT
Maximum repetitive peak reverse voltage	VRRM	70	80	90	100	V
Maximum RMS voltage	VRMS	49	56	63	70	V
Maximum DC blocking voltage	VDC	70	80	90	100	V
Maximum average forward rectified current @ T _L =100°C	IF(AV)			2.0		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	IFSM			60		A
Maximum forward voltage at 2A DC T _A =25°C T _A =100°C	VF			0.79 0.69		V
Maximum DC reverse current at rated DC blocking voltage ⁽¹⁾	T _J =25°C T _J =125°C	IR	0.05			mA
Typical junction capacitance (Note 1)	C _j		1			
Typical thermal resistance (Note 2)	R _{θJA}	85				°C/W
	R _{θJC}	45				
	R _{θJL}	40				
Operating junction temperature range	T _J		- 55 to + 150			°C
storage temperature range	T _{STG}		- 55 to + 150			°C

Notes: 1. Measured at 1.0MHZ and applied reverse voltage of 4.0V DC

2. Thermal Resistance at .375(9.5mm) Lead Length, PC Board Mounted

RATINGS AND CHARACTERISTICS CURVES**FIG.1 - FORWARD CURRENT DERATING CURVE****FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT****FIG.3 - TYPICAL JUNCTION CAPACITANCE****FIG.4 - TYPICAL FORWARD CHARACTERISTICS****FIG.5 - TYPICAL REVERSE CHARACTERISTICS**